

NEC'S NPN SILICON EPITAXIAL TRANSISTOR

NE69039

FEATURES

- OUTPUT POWER AT 1dB COMPRESSION POINT:
 27.5 dBm TYP @F = 1.9 GHz, VcE = 3.6 V, Class AB,
 Duty 1/8
- 4 PIN MINI MOLD PACKAGE: NE69039

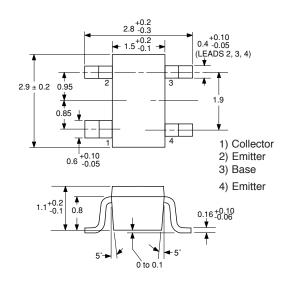
DESCRIPTION

NEC's NE69039 is a low voltage, NPN Silicon Bipolar Transistor for pulsed power applications. The device is designed to operate from a 3.6 V supply, and deliver over 1/2 watt of power output at frequencies up to 2.0 GHz with a 1:8 duty cycle. These characteristics make it an ideal device for TX output stage in a 1.9 GHz digital cordless telephone (DECT or PHS). The part is supplied in a SOT-143 (SC-61) 4-pin Minimold package and is available on tape and reel.

The NE69039 transistors are manufactured to NEC's stringent quality assurance standards to ensure highest reliability and consistent superior performance.

OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE 39



ELECTRICAL CHARACTERISTICS (TA = 25 °C)

PART NUMBER PACKAGE CODE			NE69039 39			
SYMBOLS PARAMETERS		UNITS	MIN	TYP	MAX	
Ісво	Collector Cutoff Curr	rent, VcB = 5 V, IE = 0	μΑ			2.5
IEBO	Emitter Cutoff Curre	nt, VEB = 1 V, IC = 0	μΑ			2.5
hFE	DC Current Gain, VcE = 3.6 V, Ic = 100 mA			30		
P-1	Output Power	Vce = 3.6 V, f = 1.9 GHz	dBm		27.5	
GP	Power Gain	ICq = 1 mA (Class AB)	dB	5.0	6.0	
ης	Collector Efficiency	Duty 1/8	%	50	72	
Ton	Maximum Device Or	Time	Ms			10.0

California Eastern Laboratories

ABSOLUTE MAXIMUM RATINGS¹ (TA = 25 °C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
Vсво	Collector to Base Voltage	V	9.0
VCEO	Collector to Emitter Voltage	V	6.0
VEBO	Emitter to Base Voltage	V	2.0
Ic	Collector Current	mA	300
Рт	Total Power Dissipation	mW	200 (CW)
Tj	Junction Temperature	°C	150
Тѕтс	Storage Temperature	°C	-65 to +150

Note:

 Operation in excess of any one of these parameters may result in permanent damage.

APPLICATION

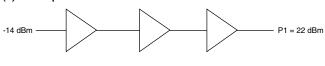
(1) TX Amplifier for DECT +3 dBm Po = 27 dBm

NE68939

(2) TX Amplifier for PHS

NE68839

μPC2771T

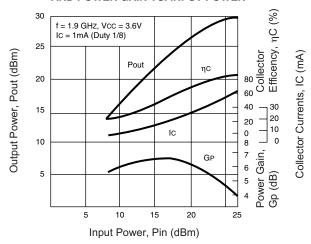


NE69039

NE69039

OUTPUT POWER, COLLECTOR EFFICIENCY, COLLECTOR CURRENT AND POWER GAIN VS. INPUT POWER

NE68939

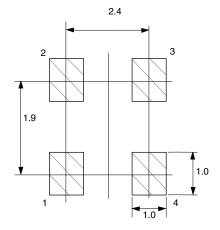


TYPICAL DATA

f = 1.9 GHz, Vcc = 3.6 V, Icq = 1 mA, DUTY = 1/8

P _{1dB}	27.5	dBm
ης	72	%
Ic	27	mA
GL	6.7	db

OUTLINE 39 RECOMMENDED P.C.B. LAYOUT



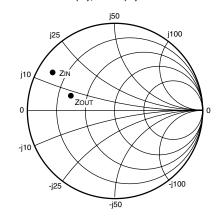
ORDERING INFORMATION

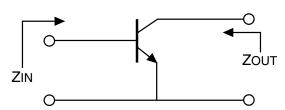
PART NUMBER	QTY
NE69039-T1-A	3K/REEL

Note:

Lead material: Cu
 Lead plating: PbSn

$\operatorname{\mathsf{Z}\!IN}(\Omega),\,\operatorname{\mathsf{Z}\!OUT}(\Omega)\operatorname{\mathsf{DATA}}$





IMPEDANCE LOOKING INTO DEVICE Vcc = 3.6 V, Icq = 1 mA, CLASS AB

FREQUENCY	ZIN	Z оит
(GHz)	(Ω)	(Ω)
1.9	7.42+j14.2	15.8-j2.64
0.9	4.0+j8.8	4.4-j4.6

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CALIFORNIA EASTERN LABORATORIES • Headquarters • 4590 Patrick Henry Drive • Santa Clara, CA 95054-1817 • (408) 988-3500 • Telex 34-6393 • FAX (408) 988-0279 24-Hour Fax-On-Demand: 800-390-3232 (U.S. and Canada only) • Internet: http://WWW.CEL.COM



4590 Patrick Henry Drive Santa Clara, CA 95054-1817 Telephone: (408) 919-2500

Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

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CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices	
Lead (Pb)	< 1000 PPM	-A -AZ Not Detected (*)	
Mercury	< 1000 PPM	Not Detected	
Cadmium	< 100 PPM	Not Detected	
Hexavalent Chromium	< 1000 PPM	Not Detected	
PBB	< 1000 PPM	Not Detected	
PBDE	< 1000 PPM	Not Detected	

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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